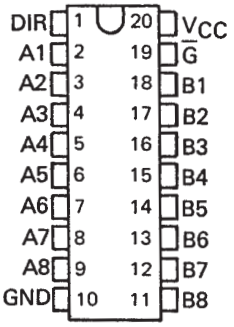
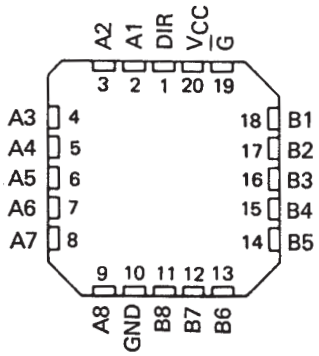
- **SN74LS64X-1 Versions Rated at I_{OL} of 48 mA**
- **Bi-directional Bus Transceivers in High-Density 20-Pin Packages**
- **Hysteresis at Bus Inputs Improves Noise Margins**
- **Choice of True or Inverting Logic**
- **Choice of 3-State or Open-Collector Outputs**

DEVICE	OUTPUT	LOGIC
'LS640	3-State	Inverting
'LS641	Open-Collector	True
'LS642	Open-Collector	Inverting
'LS644	Open-Collector	True and inverting
'LS645	3-State	True

SN54LS' . . . J PACKAGE
SN74LS' . . . DW OR N PACKAGE
(TOP VIEW)



SN54LS' . . . FK PACKAGE
(TOP VIEW)



description

These octal bus transceivers are designed for asynchronous two-way communication between data buses. The devices transmit data from the A bus to the B bus or from the B bus to the A bus depending upon the level at the direction control (DIR) input. The enable input ($\overline{G}$) can be used to disable the device so the buses are effectively isolated.

The -1 versions of the SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are identical to the standard versions except that the recommended maximum I_{OL} is increased to 48 milliamperes. There are no -1 versions of the SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645.

The SN54LS640 thru SN54LS642, SN54LS644, and SN54LS645 are characterized for operation over the full military temperature range of −55°C to 125°C. The SN74LS640 thru SN74LS642, SN74LS644, and SN74LS645 are characterized for operation from 0°C to 70°C.

FUNCTION TABLE

CONTROL INPUTS		OPERATION		
$\overline{G}$	DIR	'LS640 'LS642	'LS641 'LS645	'LS644
L	L	$\overline{B}$ data to A bus	B data to A bus	B data to A bus
L	H	$\overline{A}$ data to B bus	A data to B bus	$\overline{A}$ data to B bus
H	X	Isolation	Isolation	Isolation

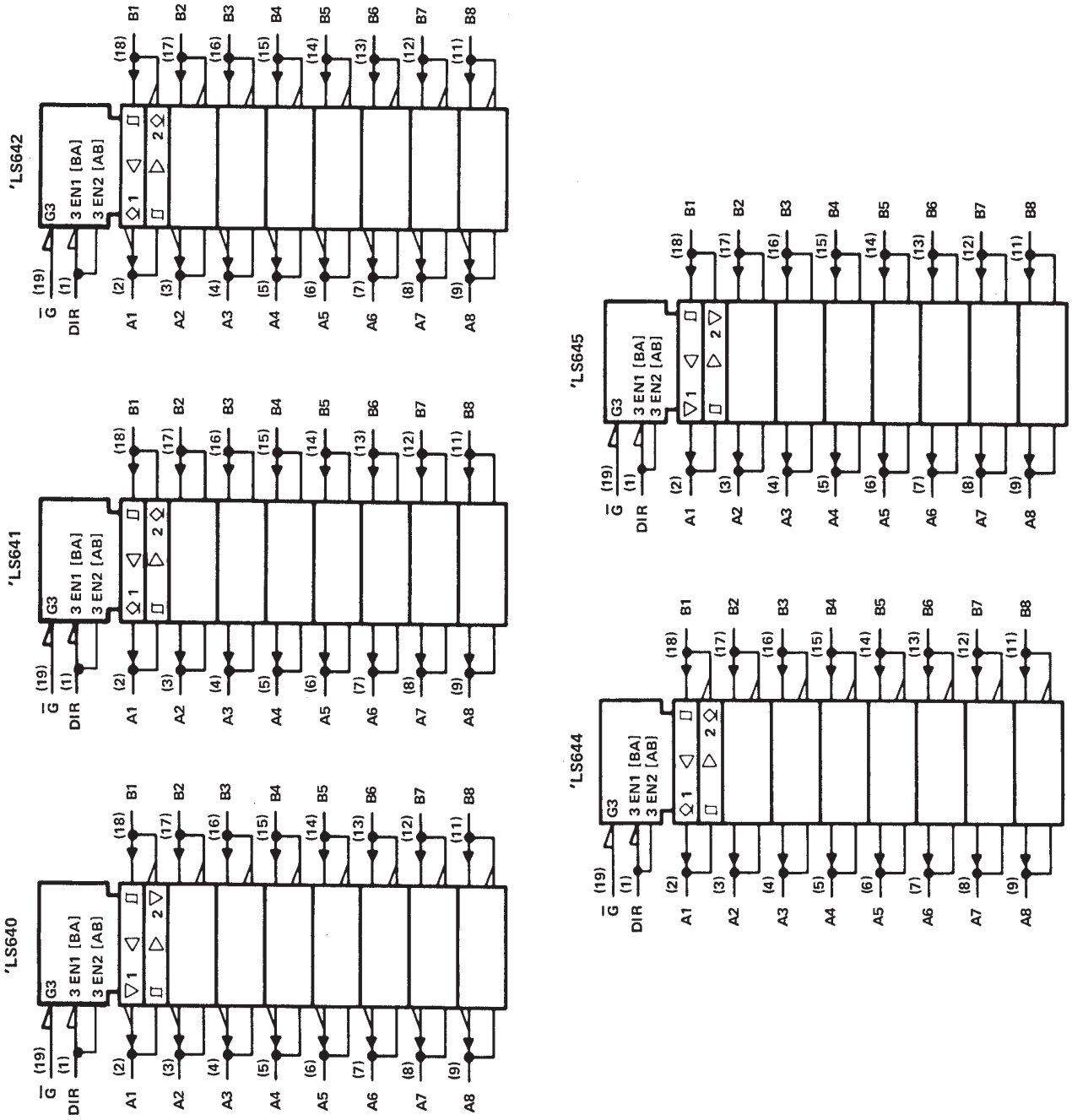
H = high level, L = low level, X = irrelevant

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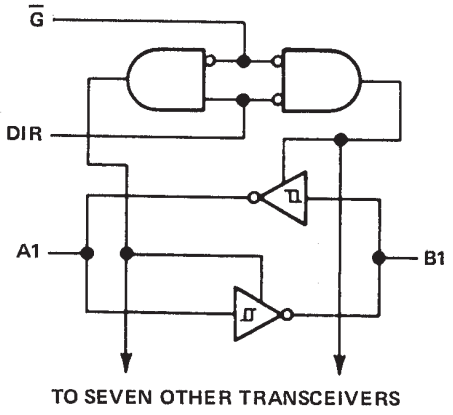
logic symbols†



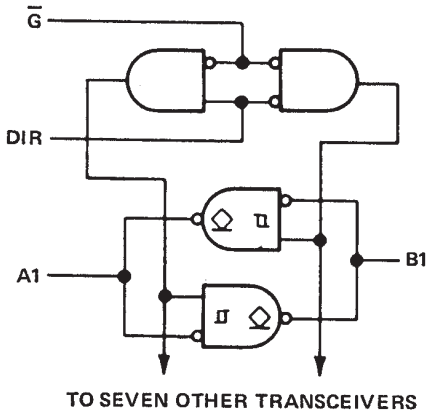
† These symbols are in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.
Pin numbers shown are for DW, J, and N packages.

logic diagrams (positive logic)

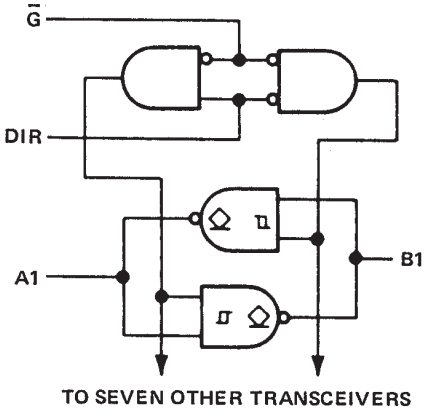
'LS640



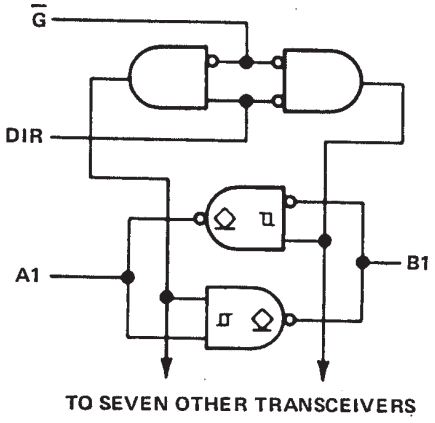
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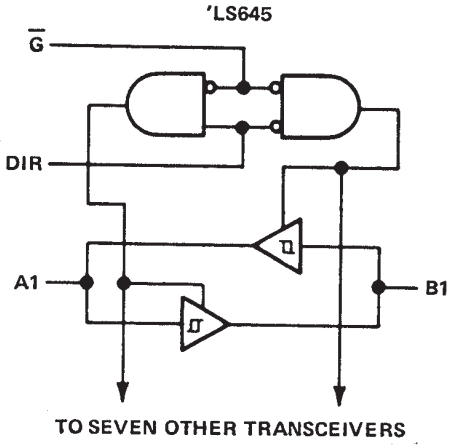
'LS642



'LS644



'LS645



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1) . . . . . 7 V
Input voltage: All inputs . . . . . 7 V
I/O ports . . . . . 5.5 V
Operating free-air temperature range: SN54LS640, SN54LS645 . . . . . −55°C to 125°C
SN74LS640, SN74LS645 . . . . . 0°C to 70°C
Storage temperature range . . . . . −65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

PARAMETER		SN54LS640 SN54LS645			SN74LS640 SN74LS645			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High-lvel input voltage	2			2			V
V_{IL}	Low-level input voltage			0.5			0.6	V
I_{OH}	High-level output current			−12			−15	mA
I_{OL}	Low-level output current			12			24	mA
							48†	
T_A	Operating free-air temperature	−55		125	0		70	°C

†The 48-mA limit applies for the SN74LS640-1 and SN74LS645-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS‡			SN54LS640 SN54LS645			SN74LS640 SN74LS645			UNIT
					MIN	TYP§	MAX	MIN	TYP§	MAX	
V_{IK}		V_{CC} = MIN, I_I = −18 mA					−1.5			−1.5	V
Hysteresis ($V_{T+} - V_{T-}$)		V_{CC} = MIN,		A or B input	0.1	0.4		0.2	0.4		V
V_{OH}		V_{CC} = MIN, V_{IH} = 2 V, V_{IL} = MAX		I_{OH} = −3 mA	2.4	3.4		2.4	3.4		
				I_{OH} = MAX	2			2			
V_{OL}		V_{CC} = MIN, V_{IH} = 2 V, V_{IL} = MAX		I_{OL} = 12 mA		0.25	0.4		0.25	0.4	V
				I_{OL} = 24 mA					0.35	0.5	
				I_{OL} = 48 mA#					0.4	0.5	
I_{OZH}		V_{CC} = MAX, $\overline{G}$ at 2 V,		V_O = 2.7 V			20			20	μA
I_{OZL}		V_{CC} = MAX, $\overline{G}$ at 2 V,		V_O = 0.4 V			−0.4			−0.4	mA
I_I	A or B	V_{CC} = MAX		V_I = 5.5 V			0.1			0.1	mA
	DIR or $\overline{G}$			V_I = 7 V			0.1			0.1	
I_{IH}		V_{CC} = MAX, V_{IH} = 2.7 V					20			20	μA
I_{IL}		V_{CC} = MAX, V_{IL} = 0.4 V					−0.4			−0.4	mA
I_{OS}¶		V_{CC} = MAX			−40		−225	−40		−225	mA
I_{CC}	Outputs high	V_{CC} = MAX, Outputs open				48	70		48	70	mA
	Outputs low					62	90		62	90	
	Outputs at Hi-Z					64	95		64	95	

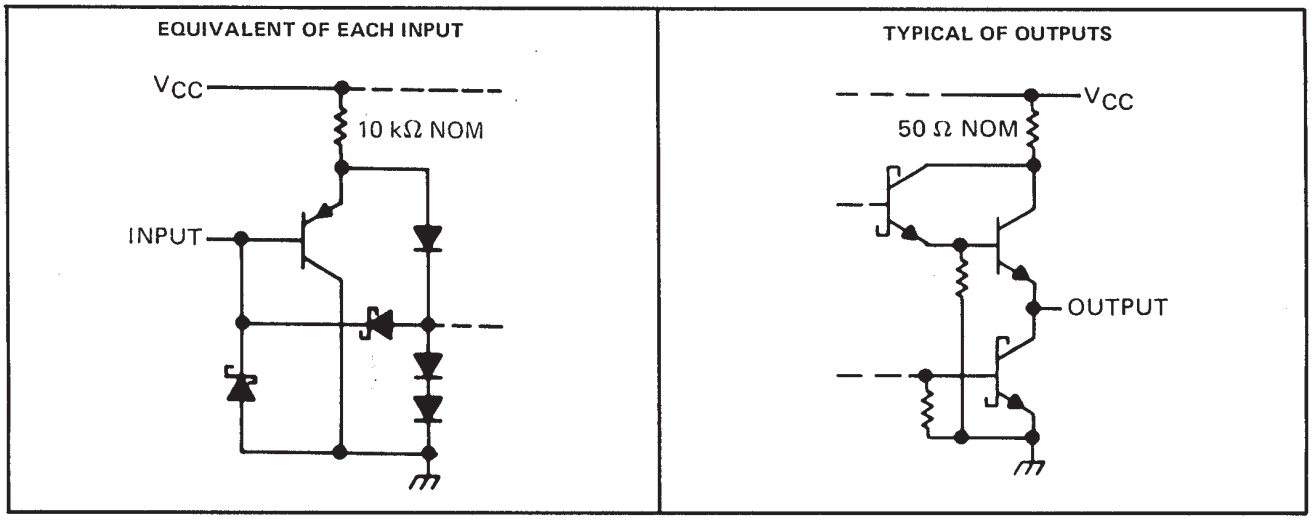
†For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
§All typical values are at V_{CC} = 5 V, T_A = 25°C.
¶Not more than one output should be shorted at a time, and duration of the short-circuit should not exceed one second.
#The 48-mA condition applies for the SN74LS640-1 and SN74LS645-1 only.

switching characteristics, V_{CC} = 5 V, T_A = 25°C

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	'LS640, 'LS640-1			'LS645, 'LS645-1			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low-to-high-level output	A	B	C_L = 45 pF, R_L = 667 Ω, See Note 2		6	10		8	15	ns
		B	A			6	10		8	15	
t_{PHL}	Propagation delay time, high-to-low-level output	A	B			8	15		11	15	ns
		B	A			8	15		11	15	
t_{PZL}	Output enable time to low level	$\overline{G}$	A			31	40		31	40	ns
		$\overline{G}$	B			31	40		31	40	
t_{PZH}	Output enable time to high level	$\overline{G}$	A			23	40		26	40	ns
		$\overline{G}$	B			23	40		26	40	
t_{PLZ}	Output disable time from low level	$\overline{G}$	A	C_L = 5 pF, R_L = 667 Ω, See Note 2		15	25		15	25	ns
		$\overline{G}$	B			15	25		15	25	
t_{PHZ}	Output disable time from high level	$\overline{G}$	A			15	25		15	25	ns
		$\overline{G}$	B			15	25		15	25	

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

schematics of inputs and outputs



TYPICAL CHARACTERISTICS

SN54LS'
INVERTING OUTPUT VOLTAGE
vs
INPUT VOLTAGE

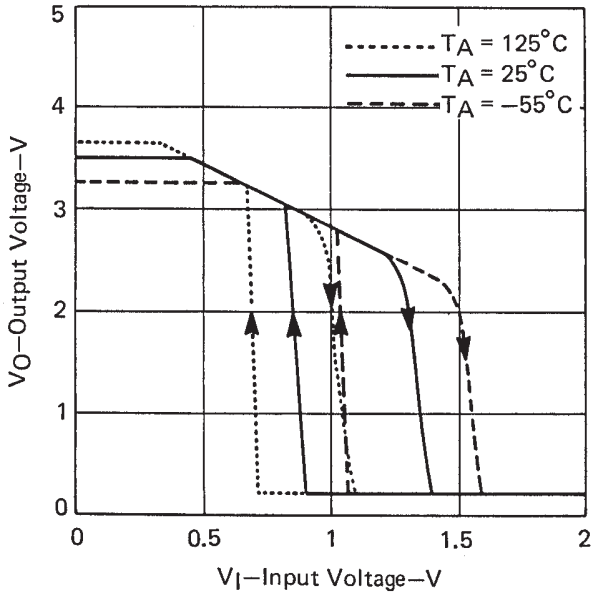


FIGURE 1

SN74LS'
INVERTING OUTPUT VOLTAGE
vs
INPUT VOLTAGE

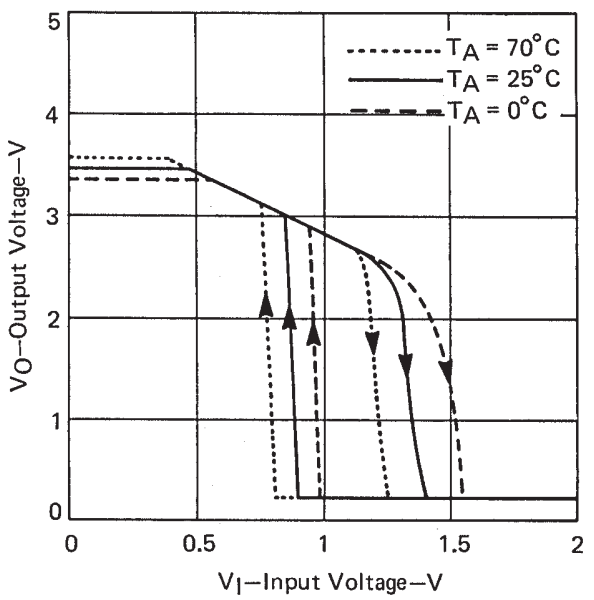


FIGURE 2

SN54LS'
NONINVERTING OUTPUT VOLTAGE
vs
INPUT VOLTAGE

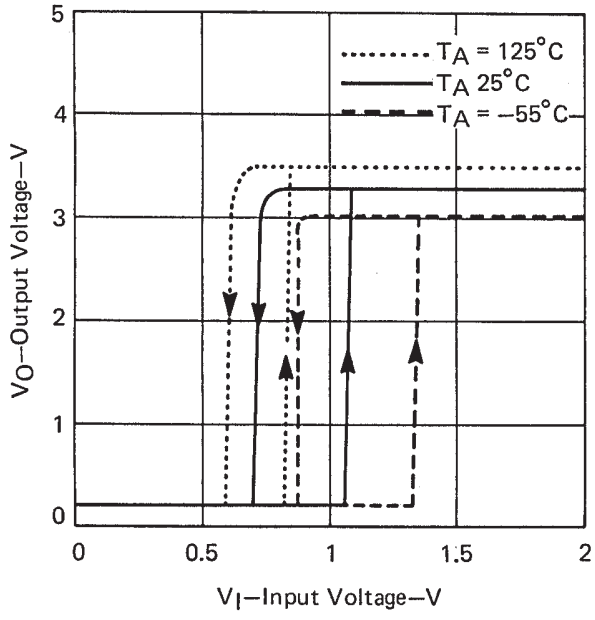


FIGURE 3

SN74LS'
NONINVERTING OUTPUT VOLTAGE
vs
INPUT VOLTAGE

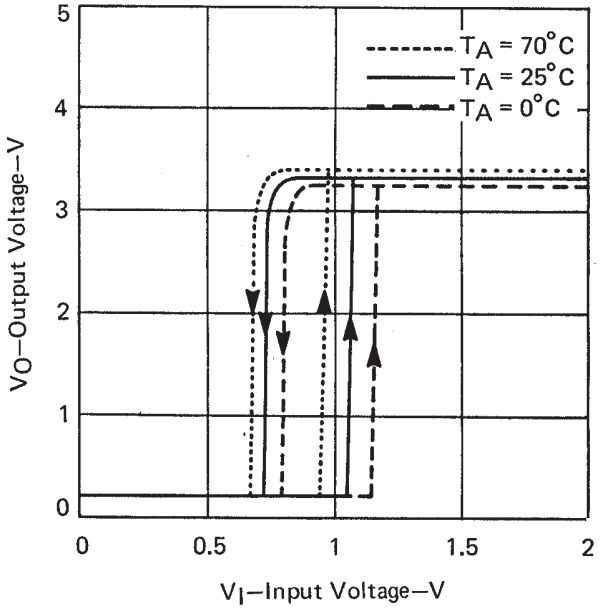


FIGURE 4

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)

Supply voltage, V_{CC} (see Note 1) . . . . . 7 V
Input voltage: All inputs and I/O ports . . . . . 7 V
Operating free-air temperature range: SN54LS641, SN54LS642, SN54LS644 . . . . . – 55°C to 125°C
SN74LS641, SN74LS642, SN74LS644 . . . . . 0°C to 70°C
Storage temperature range . . . . . – 65°C to 150°C

NOTE 1: Voltage values are with respect to network ground terminal.

recommended operating conditions

PARAMETER		SN54LS641 SN54LS642 SN54LS644			SN74LS641 SN74LS642 SN74LS644			UNIT
		MIN	NOM	MAX	MIN	NOM	MAX	
V_{CC}	Supply voltage	4.5	5	5.5	4.75	5	5.25	V
V_{IH}	High-level input voltage	2			2			V
V_{IL}	Low-level input voltage			0.5			0.6	V
V_{OH}	High-level output voltage			5.5			5.5	V
I_{OL}	Low-level output current			12			24	mA
							48§	
T_A	Operating free-air temperature	– 55		125	0		70	°C

§The 48 mA limit applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS†		SN54LS641 SN54LS642 SN54LS644			SN74LS641 SN74LS642 SN74LS644			UNIT
				MIN	TYP‡	MAX	MIN	TYP‡	MAX	
V_{IK}		V_{CC} = MIN,	I_I = – 18 mA			– 1.5			– 1.5	V
Hysteresis ($V_{T+} - V_{T-}$)		V_{CC} = MIN,	A or B input	0.1	0.4		0.2	0.4		V
I_{OH}		V_{CC} = MIN, V_{IL} = MAX,	V_{IH} = 2 V, V_{OH} = 5.5 V			0.1			0.1	mA
V_{OL}		V_{CC} = MIN, V_{IH} = 2 V, V_{IL} = MAX	I_{OL} = 12 mA		0.25	0.4		0.25	0.4	V
			I_{OL} = 24 mA					0.35	0.5	
			I_{OL} = 48 mA§					0.4	0.5	
I_I	A or B	V_{CC} = MAX	V_I = 5.5 V			0.1			0.1	mA
	DIR or $\overline{G}$		V_I = 7 V			0.1			0.1	
I_{IH}		V_{CC} = MAX,	V_I = 2.7 V			20			20	μA
I_{IL}		V_{CC} = MAX,	V_I = 0.4 V			– 0.4			– 0.4	mA
I_{CC}	Outputs high	V_{CC} = MAX,	Outputs open		48	70		48	70	mA
	Outputs low				62	90		62	90	
	Outputs at Hi-Z				64	95		64	95	

† For conditions shown as MIN or MAX, use the appropriate value specified under recommended operating conditions.
‡ All typical values are at V_{CC} = 5 V, T_A = 25°C.
§The 48 mA condition applies for the SN74LS641-1, SN74LS642-1, and SN74LS644-1 only.

switching characteristics at V_{CC} = 5 V, T_A = 25°C

PARAMETER		FROM (INPUT)	TO (OUTPUT)	TEST CONDITIONS	'LS641, 'LS641–1			'LS642, 'LS642–1			'LS644, 'LS644–1			UNIT
					MIN	TYP	MAX	MIN	TYP	MAX	MIN	TYP	MAX	
t_{PLH}	Propagation delay time, low-to-high-level output	A	B	C_L = 45 pF, R_L = 667 Ω, See Note 2		17	25		19	25		17	25	ns
		B	A			17	25		19	25		19	25	
t_{PHL}	Propagation delay time, high-to-low-level output	A	B			16	25		14	25		14	25	ns
		B	A			16	25		14	25		16	25	
t_{PLH}	Output disable time from low level	$\overline{G}$, DIR	A			23	40		26	40		26	40	ns
		$\overline{G}$, DIR	B			25	40		28	40		25	40	
t_{PHL}	Output enable time from high level	$\overline{G}$, DIR	A			34	50		43	60		43	60	ns
		$\overline{G}$, DIR	B			37	50		39	60		37	50	

NOTE 2: Load circuits and voltage waveforms are shown in Section 1.

schematics of inputs and outputs

EQUIVALENT OF EACH INPUT

TYPICAL OF OUTPUTS

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